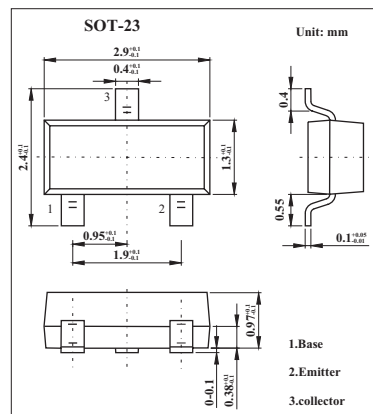


# 2SA1365

### ■ Features

- Low collector to emitter saturation voltage.
- Excellent linearity of DC forward current gain.
- Super mini package for easy mounting.
- High collector current.
- High gain band width product.



### ■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	-25	V
Collector-emitter voltage	V <sub>CEO</sub>	-20	V
Emitter-base voltage	V <sub>EBO</sub>	-4	V
Peak collector current	I <sub>CM</sub>	-1	A
Collector current	I <sub>C</sub>	-700	mA
Collector dissipation (Ta=25°C)	P <sub>C</sub>	150	mW
Junction temperature	T <sub>j</sub>	125	°C
Storage temperature	T <sub>stg</sub>	-55 to +125	°C

### ■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Testconditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V (BR) CBO	I <sub>C</sub> = -10 μA, I <sub>E</sub> = 0	-25			V
Collector-emitter breakdown voltage	V (BR) CEO	I <sub>C</sub> = -100 μA, R <sub>BE</sub> = ∞	-20			V
Emitter-base breakdown voltage	V (BR) EBO	I <sub>E</sub> = -10 μA, I <sub>C</sub> = 0	-4			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = -25 V, I <sub>E</sub> = 0			-1	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = -2 V, I <sub>C</sub> = 0			-1	μA
DC current gain ( * )	h <sub>FE</sub>	V <sub>CE</sub> = -4 V, I <sub>C</sub> = -100 mA	150		800	
Collector-emitter saturation voltage	V <sub>CE</sub>	I <sub>C</sub> = -500 mA, I <sub>B</sub> = -25 mA		-0.2	-0.5	V
Gain band width product	f <sub>T</sub>	V <sub>CE</sub> = -6 V, I <sub>E</sub> = 10 mA		180		MHz

\* It shows h<sub>FE</sub> classification in right table.

### ■ hFE Classification

Marking	AE	AF	AG
hFE	150~300	250~500	400~800